imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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SOP-8 8

Pin Definition:



8. Drain 1 1. Source 1 2. Gate 1 7. Drain 1 6. Drain 2 3. Source 2

4. Gate 2 5. Drain 2

Features

- Advance Trench Process Technology •
- High Density Cell Design for Ultra Low On-resistance •

Application

- Load Switch •
- PA Switch

Ordering Information

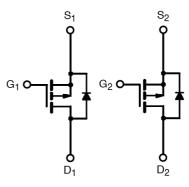
Part No.	Package	Packing
TSM4953DCS RLG	SOP-8	2.5Kpcs / 13" Reel

Note: "G" denotes Halogen Free Product.

PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (mΩ)	I _D (A)
	60 @ V _{GS} = 10V	-4.9
-30	90 @ V _{GS} = 4.5V	-3.7

Block Diagram



Dual P-Channel MOSFET

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	-30	V
Gate-Source Voltage		V _{GS}	±20	V
Continuous Drain Current, V_{GS} @4.5V.		I _D	-4.9	А
Pulsed Drain Current, V _{GS} @4.5V		I _{DM}	-20	А
Continuous Source Current (Diode Con	iduction) ^{a,b}	I _S	-2.6	А
Maximum Power Dissipation	Ta = 25°C	P _D	2.5	W
	Ta = 70°C		1.3	
Operating Junction Temperature		TJ	+150	°C
Operating Junction and Storage Tempe	erature Range	T _J , T _{STG}	- 55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	RƏ _{JC}	40	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	RƏ _{JA}	62.5	°C/W

Notes:

a. Pulse width limited by the Maximum junction temperature

b. Surface Mounted on FR4 Board, $t \le 5$ sec.



Electrical Specifications (Ta = 25°C unless otherwise noted)

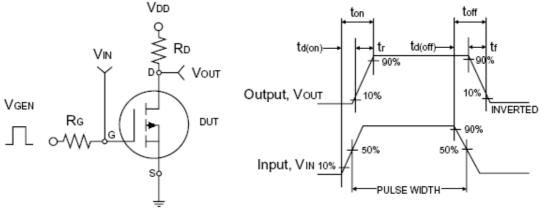
Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static				•		
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{D} = -250uA$	BV _{DSS}	-30			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, \ I_D = -250 \mu A$	V _{GS(TH)}	-1.0	-1.5	-3.0	V
Gate Body Leakage	$V_{GS}=\pm 20V,\ V_{DS}=0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -24V, V_{GS} = 0V$	I _{DSS}			-1.0	μA
On-State Drain Current ^a	$V_{DS} = -5V, V_{GS} = -10V$	I _{D(ON)}	-6			А
Ducia Courses On Otata Desistance a	$V_{GS} = -10V, I_D = -4.9A$			50	60	mΩ
Drain-Source On-State Resistance ^a	$V_{GS} = -4.5V, I_{D} = -3.7A$	R _{DS(ON)}		75	90	
Forward Transconductance ^a	$V_{DS} = -15V, I_{D} = -4.9A$	g _{fs}		10		S
Diode Forward Voltage	$I_{\rm S}$ = -1.9A, $V_{\rm GS}$ = 0V	V _{SD}			-1.3	V
Dynamic						
Total Gate Charge		Qg		28		
Gate-Source Charge	$V_{DS} = -15V, I_D = -4.9A,$ $V_{GS} = -10V$	Q _{gs}		3		nC
Gate-Drain Charge		Q _{gd}		7		
Input Capacitance	$V_{DS} = -15V, V_{GS} = 0V,$ f = 1.0MHz	C _{iss}		745		
Output Capacitance		C _{oss}		440		pF
Reverse Transfer Capacitance		C _{rss}		120		
Switching						
Turn-On Delay Time	$V_{DD} = -15V, R_L = 15\Omega,$ $I_D = -1A, V_{GEN} = -10V,$ $R_G = 6\Omega$	t _{d(on)}		9		
Turn-On Rise Time		t _r		15		
Turn-Off Delay Time		t _{d(off)}		75		nS
Turn-Off Fall Time		t _f		40		

Notes:

1. pulse test: PW \leq 300µS, duty cycle \leq 2%

2. For DESIGN AID ONLY, not subject to production testing.

3. Switching time is essentially independent of operating temperature.

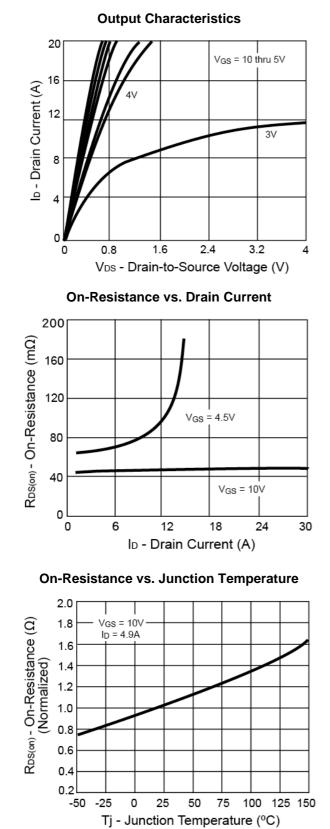


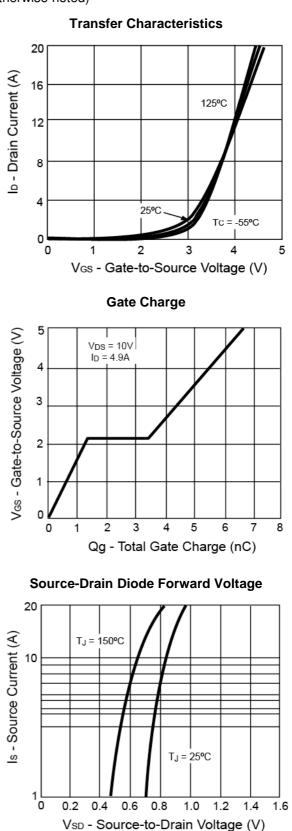
Switching Test Circuit

Switchin Waveforms



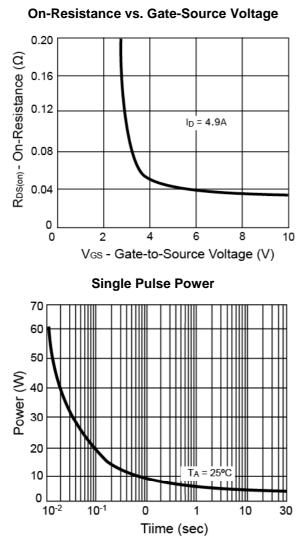
Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

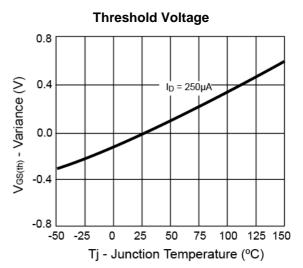




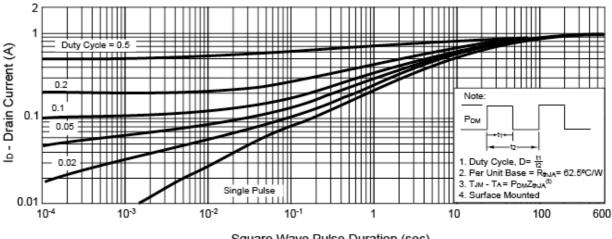


Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)





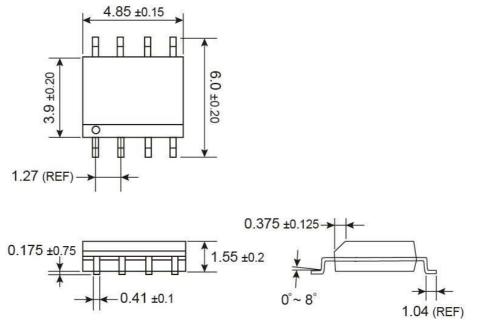
Normalized Thermal Transient Impedance, Junction-to-Ambient



Square Wave Pulse Duration (sec)



SOP-8 Mechanical Drawing



Unit: Millimeters

Marking Diagram

日日日日 TSM4953D	Y = Year CodeM = Month Code for Halogen Free Product			
1310149550	O =Jan	P =Feb Q =Mar	R =Apr	
	S =May	T =Jun U =Jul	V =Aug	
	W =Sep	X =Oct Y =Nov	Z =Dec	
	L = Lot Code			



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